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# Lecture8: MOSFET, IV

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# Derivation of IV (1/2)

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- Drain current

- First of all, the current is given by

$$I = Q_{elec} v \quad (6.4)$$

- Here,  $Q_{elec}$  is the electron charge density *per unit length*.
- It follows

$$Q_{elec} = WC_{ox}[V_G - V(x) - V_{TH}] \quad (6.3)$$

- Also  $v$  is the electron velocity.

$$v = -\mu_n E = +\mu_n \frac{dV}{dx} \quad (6.5 \text{ and } 6.6)$$

- The drain current is

$$I_D = WC_{ox}[V_G - V(x) - V_{TH}]\mu_n \frac{dV}{dx} \quad (6.7)$$

# Derivation of IV (2/2)

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- Integration over the channel

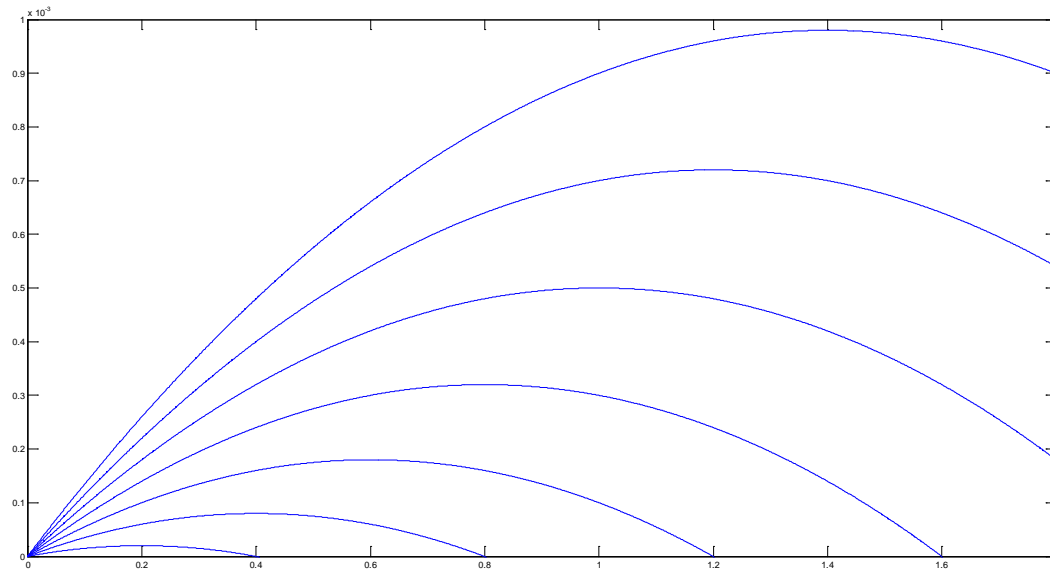
- Simply re-arranging,

$$I_D dx = \mu_n C_{ox} W [V_G - V(x) - V_{TH}] dV$$

- When integrated,

$$I_D = \mu_n C_{ox} \frac{W}{L} \left[ (V_G - V_{TH}) V_{DS} - \frac{1}{2} V_{DS}^2 \right]$$

Current



← Is it acceptable?

Voltage

# Of course, not!

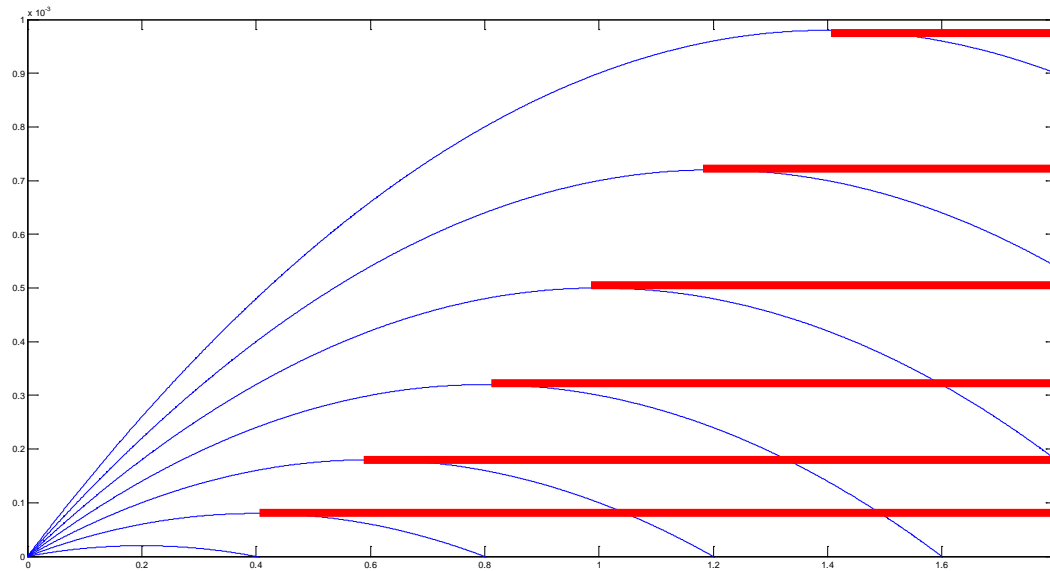
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- Current usually increases as the voltage increases...
- Recall (6.3).

$$Q = WC_{ox}[V_G - V(x) - V_{TH}] \quad (6.3)$$

- What happens when  $V(x) = V_G - V_{TH}$ ?
- “Saturation region”

Current



← Instead, the current is saturated. (Red lines)

Voltage

# Example 6.6 (Razavi)

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- Assume the saturation region.
  - Then, the saturation current becomes  $200\ \mu\text{A}$ .

